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# LM567/LM567C Tone Decoder

## **General Description**

The LM567 and LM567C are general purpose tone decoders designed to provide a saturated transistor switch to ground when an input signal is present within the passband. The circuit consists of an I and Q detector driven by a voltage controlled oscillator which determines the center frequency of the decoder. External components are used to independently set center frequency, bandwidth and output delay.

#### **Features**

- 20 to 1 frequency range with an external resistor
- Logic compatible output with 100 mA current sinking capability
- Bandwidth adjustable from 0 to 14%

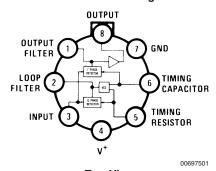
- High rejection of out of band signals and noise
- Immunity to false signals
- Highly stable center frequency
- Center frequency adjustable from 0.01 Hz to 500 kHz

## **Applications**

- Touch tone decoding
- Precision oscillator
- Frequency monitoring and control
- Wide band FSK demodulation
- Ultrasonic controls
- Carrier current remote controls
- Communications paging decoders

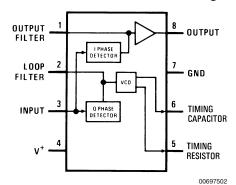
## **Connection Diagrams**

#### Metal Can Package



Top View Order Number LM567H or LM567CH See NS Package Number H08C

#### **Dual-In-Line and Small Outline Packages**



Top View
Order Number LM567CM
See NS Package Number M08A
Order Number LM567CN
See NS Package Number N08E

## **Absolute Maximum Ratings** (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage Pin 9V Power Dissipation (Note 2) 1100 mW  $V_8$  15V  $V_3$  -10V  $V_3$   $V_4 + 0.5$ V Storage Temperature Range  $-65^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ 

Operating Temperature Range

Soldering Information

Dual-In-Line Package

Soldering (10 sec.) 260°C

Small Outline Package

 Vapor Phase (60 sec.)
 215°C

 Infrared (15 sec.)
 220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

## **Electrical Characteristics**

AC Test Circuit,  $T_A = 25$ °C,  $V^+ = 5V$ 

Parameters	Conditions	LM567			LM567C/LM567CM			11
		Min	Тур	Max	Min	Тур	Max	Units
Power Supply Voltage Range		4.75	5.0	9.0	4.75	5.0	9.0	V
Power Supply Current Quiescent	R <sub>L</sub> = 20k		6	8		7	10	mA
Power Supply Current Activated	R <sub>L</sub> = 20k		11	13		12	15	mA
Input Resistance		18	20		15	20		kΩ
Smallest Detectable Input Voltage	$I_L = 100 \text{ mA}, f_i = f_o$		20	25		20	25	mVrms
Largest No Output Input Voltage	$I_{\rm C} = 100$ mA, $f_{\rm i} = f_{\rm o}$	10	15		10	15		mVrms
Largest Simultaneous Outband Signal to Inband Signal Ratio			6			6		dB
Minimum Input Signal to Wideband Noise Ratio	B <sub>n</sub> = 140 kHz		-6			-6		dB
Largest Detection Bandwidth		12	14	16	10	14	18	% of f <sub>o</sub>
Largest Detection Bandwidth Skew			1	2		2	3	% of f <sub>o</sub>
Largest Detection Bandwidth Variation with Temperature			±0.1			±0.1		%/°C
Largest Detection Bandwidth Variation with Supply Voltage	4.75-6.75V		±1	±2		±1	±5	%V
Highest Center Frequency		100	500		100	500		kHz
Center Frequency Stability (4.75–5.75V)	$0 < T_A < 70$ -55 < $T_A < +125$		35 ± 60 35 ± 140			35 ± 60 35 ± 140		ppm/°C ppm/°C
Center Frequency Shift with Supply	4.75V-6.75V		0.5	1.0		0.4	2.0	%/V
Voltage	4.75V-9V			2.0			2.0	%/V
Fastest ON-OFF Cycling Rate			f <sub>o</sub> /20			f <sub>o</sub> /20		
Output Leakage Current	V <sub>8</sub> = 15V		0.01	25		0.01	25	μΑ
Output Saturation Voltage	$e_i = 25 \text{ mV}, I_8 = 30 \text{ mA}$		0.2	0.4		0.2	0.4	l v l
	$e_i = 25 \text{ mV}, I_8 = 100 \text{ mA}$		0.6	1.0		0.6	1.0	v
Output Fall Time			30			30		ns
Output Rise Time			150			150		ns

**Note 1:** Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. Electrical Characteristics state DC and AC electrical specifications under particular test conditions which guarantee specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not guaranteed for parameters where no limit is given, however, the typical value is a good indication of device performance.

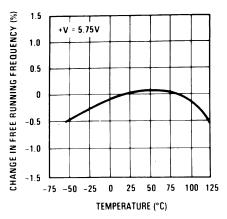
Note 2: The maximum junction temperature of the LM567 and LM567C is 150°C. For operating at elevated temperatures, devices in the TO-5 package must be derated based on a thermal resistance of 150°C/W, junction to ambient or 45°C/W, junction to case. For the DIP the device must be derated based on a thermal resistance of 110°C/W, junction to ambient. For the Small Outline package, the device must be derated based on a thermal resistance of 160°C/W, junction to ambient

Note 3: Refer to RETS567X drawing for specifications of military LM567H version.

# **Schematic Diagram** R10 ₹ R11 ₹ ₹ R3 4.7K Q53 Q61 Q62 R36 \ R37 Q59 R20 **₹ ≹** R22 ₹R31 **₹** R45 023 -**V**V R30 R29 ₹R32 048 032 Q6 043 **₹**R23 R26 **≷** 040 **≸**R34 Q5 031 R24 ≸ R28 ≸

# **Typical Performance Characteristics**

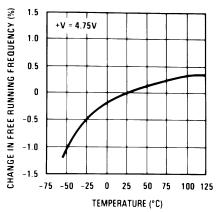
#### **Typical Frequency Drift**



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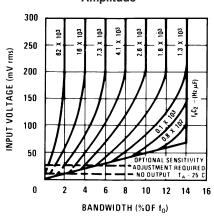
#### 69/510

#### **Typical Frequency Drift**



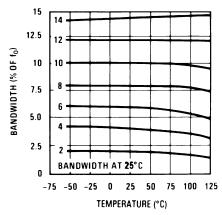
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#### Bandwidth vs Input Signal Amplitude



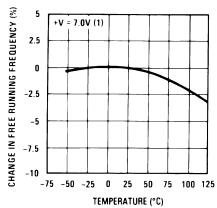
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#### **Typical Bandwidth Variation**



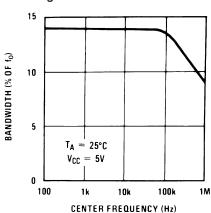
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#### **Typical Frequency Drift**



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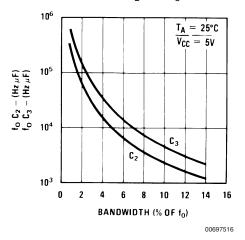
#### **Largest Detection Bandwidth**



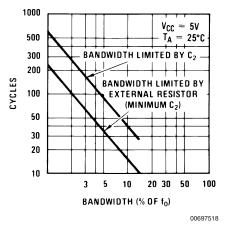
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# **Typical Performance Characteristics** (Continued)

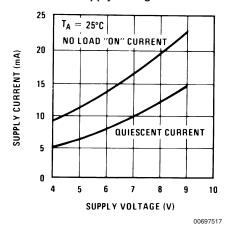
# Detection Bandwidth as a Function of C<sub>2</sub> and C<sub>3</sub>



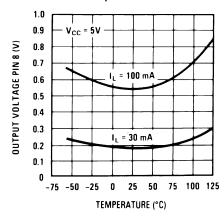
#### Greatest Number of Cycles Before Output



#### Typical Supply Current vs Supply Voltage



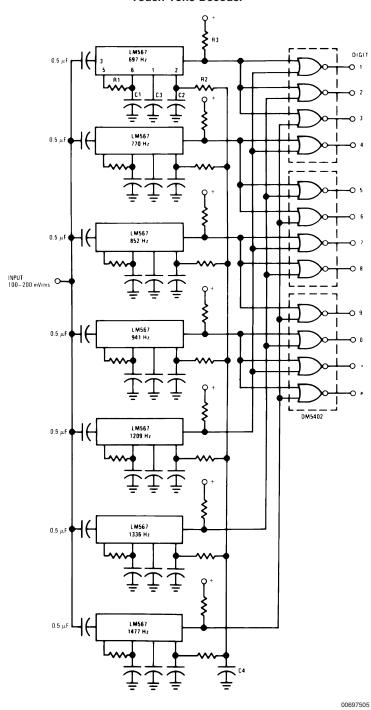
#### Typical Output Voltage vs Temperature



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# **Typical Applications**

#### **Touch-Tone Decoder**



Component values (typ)

R1 6.8 to 15k

R2 4.7k

R3 20k

C1 0.10 mfd

C2 1.0 mfd 6V

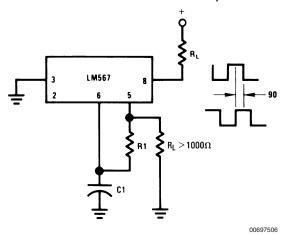
C3 2.2 mfd 6V

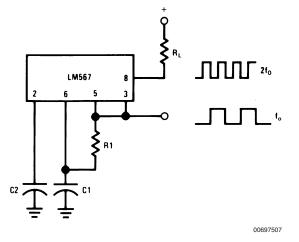
C4 250 mfd 6V

# Typical Applications (Continued)

#### Oscillator with Double Frequency Output

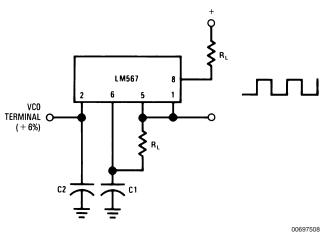
#### Oscillator with Quadrature Output



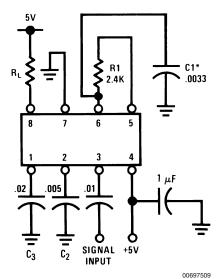


Connect Pin 3 to 2.8V to Invert Output

#### Precision Oscillator Drive 100 mA Loads



## **AC Test Circuit**



 $f_i = 100 \text{ kHz} + 5 \text{V}$ 

\*Note: Adjust for f<sub>0</sub> = 100 kHz.

# **Applications Information**

The center frequency of the tone decoder is equal to the free running frequency of the VCO. This is given by

$$f_o \cong \frac{1}{1.1 R_1 C_1}$$

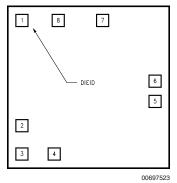
The bandwidth of the filter may be found from the approximation

BW = 1070 
$$\sqrt{\frac{V_i}{f_o C_2}}$$
 in % of  $f_o$ 

Where:

 $\begin{aligned} V_i &= \text{Input voltage (volts rms)}, \ V_i \leq 200 \text{mV} \\ C_2 &= \text{Capacitance at Pin 2}(\mu\text{F}) \end{aligned}$ 

# LM567C MDC MWC TONE DECODER



Die Layout (C - Step)

## **DIE/WAFER CHARACTERISTICS**

Fabrication Attributes		General Die Information			
Physical Die Identification	LM567C	Bond Pad Opening Size (min)	91µm x 91µm		
Die Step	С	Bond Pad Metalization	0.5% COPPER_BAL. ALUMINUM		
Physical Attributes		Passivation	VOM NITRIDE		
Wafer Diameter	150mm	Back Side Metal	BARE BACK		
Dise Size (Drawn)	1600µm x 1626µm 63.0mils x 64.0mils	Back Side Connection	Floating		
Thickness	406µm Nominal				
Min Pitch	198µm Nominal				

#### **Special Assembly Requirements:**

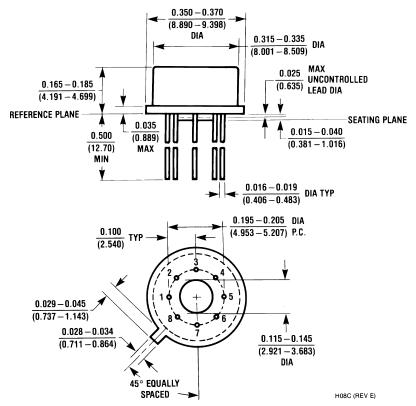
Note: Actual die size is rounded to the nearest micron.

Die Bond Pad Coordinate Locations (C - Step)							
(Referenced to die center, coordinates in μm) NC = No Connection, N.U. = Not Used							
SIGNAL NAME	PAD# NUMBER	X/Y COORDINATES		PAD SIZE			
		Х	Υ	Х		Υ	
OUTPUT	1	-673	686	91	х	91	
FILTER							
LOOP FILTER	2	-673	-419	91	x	91	
INPUT	3	-673	-686	91	х	91	
V+	4	-356	-686	91	х	91	
TIMING RES	5	673	-122	91	х	91	
TIMING CAP	6	673	76	91	х	91	
GND	7	178	686	117	Х	91	
OUTPUT	8	-318	679	117	Х	104	

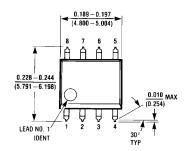
# LM567C MDC MWC TONE DECODER (Continued)

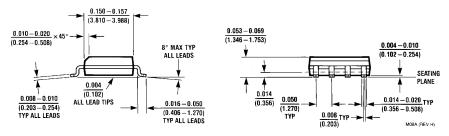
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# **Physical Dimensions** inches (millimeters) unless otherwise noted



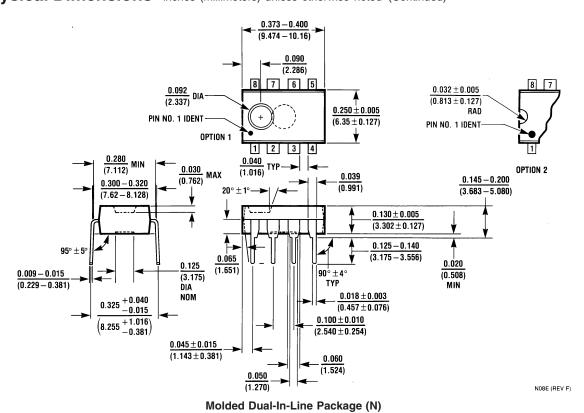
Metal Can Package (H) Order Number LM567H or LM567CH **NS Package Number H08C** 





Small Outline Package (M) Order Number LM567CM **NS Package Number M08A** 

### Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



National does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and National reserves the right at any time without notice to change said circuitry and specifications.

Order Number LM567CN NS Package Number N08E

For the most current product information visit us at www.national.com.

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